AN   127:74284 CA
ED   Entered STN: 29 Jul 1997
TI   Thin-film transistor for light-weight liquid-crystal display
IN   Mimura, Akio; Shinagawa, Takaaki
PA   Hitachi, Ltd., Japan
SO   Jpn. Kokai Tokkyo Koho, 6 pp.
·   CODEN: JKXXAF
DT   Patent
LA   Japanese
IC   ICM H01L029-786
      ICS H01L021-336; G02F001-136; H01L021-20; H01L021-268; H01L027-12
CC   76-3 (Electric Phenomena)
      Section cross-reference(s): 74
FAN.CNT 1

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
PI JP 09116158	A2	19970502	JP 1995-268668	19951017
PRAI JP 1995-268668		19951017		

CLASS

PATENT NO.	CLASS	PATENT FAMILY CLASSIFICATION CODES
JP 09116158	ICM	H01L029-786
	ICS	H01L021-336; G02F001-136; H01L021-20; H01L021-268; H01L027-12

AB   The invention relates to a thin-film semiconductor device, suited for use
      as a poly-Si TFT driver for light-wt. active-matrix liq.-crystal displays,
      wherein the substrate for the TFT array consists of a plastic board or a
      flexible glass plate .ltoreq. 0.5 mm thick.
ST   thin film transistor liq crystal display; polysilicon TFT light wt LCD
IT   Liquid crystal displays
          (active-matrix; poly-Si TFT driver for light-wt. active-matrix
          liq.-crystal display)
IT   Thin film transistors
          (poly-Si TFT driver for light-wt. active-matrix liq.-crystal display)
IT   7440-21-3, Silicon, uses